













#### REF3012, REF3020, REF3025, REF3030, REF3033, REF3040

SBVS032G - MARCH 2002 - REVISED NOVEMBER 2015

# REF30xx 50-ppm/°C Max, 50-µA, CMOS Voltage Reference in SOT-23-3

#### **Features**

microSize Package: SOT-23-3

Low Dropout: 1 mV

High Output Current: 25 mA

High Accuracy: 0.2% Low  $I_0$ : 42  $\mu$ A (typ)

**Excellent Specified Drift Performance:** 

50 ppm/°C (max) from 0°C to 70°C

75 ppm/°C (max) from –40°C to +125°C

### **Applications**

- Temperature and Pressure Transmitters
- Portable, Battery-powered Equipment
- **Data Acquisition Systems**
- Medical Equipment
- Handheld Test Equipment

### 3 Description

The REF30xx is a precision, low-power, low dropout voltage, reference family available in a tiny SOT-23-3 package. The REF30xx offers excellent temperature drift and initial accuracy while operating at a quiescent current of 42 µA (typ).

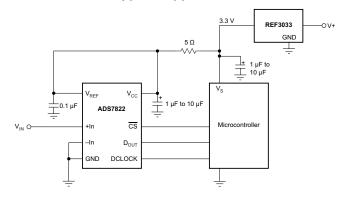
The low power consumption and the relatively high precision make the REF30xx very attractive for looppowered industrial applications such as pressure and temperature transmitter applications. The REF30xx is easy to use in intrinsically safe and explosion-proof applications because it does not require a load capacitor to be stable. The REF30xx is specified over the extended industrial temperature range of -40°C to +125°C.

The REF30xx operates with supplies within 1 mV of output voltage under zero-load conditions. The low dropout along with small size and low power consumption make The REF30xx ideal for portable and battery-powered applications.

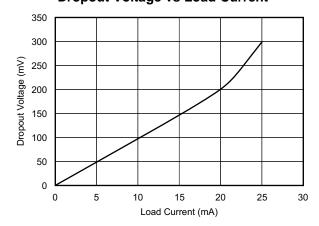
#### **Device Information**

PART NUMBER	PACKAGE	BODY SIZE (NOM)		
REF30xx	SOT-23 (3)	2.92 mm × 1.30 mm		

#### **Typical Application**



### **Dropout Voltage vs Load Current**





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### **4 Revision History**

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

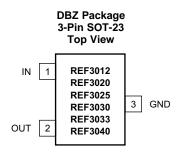
Cr	nanges from Revision F (August 2008) to Revision G	Page
•	Added Device Information, ESD Ratings, Recommended Operating Conditions, and Thermal Information tables	1
•	Added Detailed Description, Applications and Implementation, Power-Supply Recommendations, Layout, Device and Documentation Support, and Mechanical, Packaging, and Orderable Information sections	1
•	Changed text in Description section	1
•	Deleted thermal resistance parameter in Electrical Characteristics; see new Thermal Information table	6
•	Moved temperature parameters from Electrical Characteristics to Recommended Operating Conditions	6



### 5 Device Comparison Table

PART NUMBER	VOLTAGE (V)
REF3012	1.25
REF3020	2.048
REF3025	2.5
REF3030	3.0
REF3033	3.3
REF3040	4.096

### 6 Pin Configuration and Functions



#### **Pin Functions**

PIN		I/O	DESCRIPTION					
NO.	NAME	1/0	DESCRIPTION					
1	IN	Input	nput supply voltage					
2	OUT	Output	Reference output voltage					
3	GND		Ground					



### 7 Specifications

#### 7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

	MIN	MAX	UNIT
Supply voltage, V+ to V-		7.0	V
Output short-circuit current <sup>(2)</sup>		Continuous	
Operating temperature	-40	125	°C
Junction temperature		150	°C
Storage temperature, T <sub>stg</sub>	-65	150	°C

<sup>(1)</sup> Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

### 7.2 ESD Ratings

			VALUE	UNIT
V	Floatractatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 (1)	±4000	.,
V <sub>(ESD)</sub>	Electrostatic discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 (2)	±1500	V 

<sup>(1)</sup> JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

### 7.3 Recommended Operating Conditions

at  $T_A = 25$ °C,  $V_{IN} = 5$  V, and  $I_{LOAD} = 0$  mA (unless otherwise noted)

		MIN	NOM MAX	UNIT
$V_{IN}$	Input voltage	V <sub>REF</sub> + 0.05 <sup>(1)</sup>	5.5	V
I <sub>LOAD</sub>	Load current		25	mA
T <sub>A</sub>	Operating temperature	-40	125	°C

<sup>(1)</sup> For I<sub>I</sub> > 0, see *Typical Characteristics*. Minimum supply voltage for REF3012 is 1.8 V .

#### 7.4 Thermal Information

		REF30xx	
	THERMAL METRIC <sup>(1)</sup>	DBZ (SOT-23)	UNIT
		3 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	297.3	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	128.5	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	91.7	°C/W
ΨЈТ	Junction-to-top characterization parameter	12.8	°C/W
ΨЈВ	Junction-to-board characterization parameter	90.3	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	N/A	°C/W

For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.

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<sup>(2)</sup> Short circuit to ground.

<sup>(2)</sup> JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



### 7.5 Electrical Characteristics

at  $T_A = 25$  °C,  $V_{IN} = 5$  V, and  $I_{LOAD} = 0$  mA (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
REF3012	! (1.25 V) <sup>(1)</sup>					
V <sub>OUT</sub>	Output voltage		1.2475	1.25	1.2525	V
	Initial accuracy	25 V)(f)  Output voltage	0.2%			
	0.1.1.1	f = 0.1 Hz to 10 Hz		14		$\mu V_{PP}$
	Output voltage noise	f = 10 Hz to 10 kHz		42		μVrms
	Line regulation	1.8 V ≤ V <sub>IN</sub> ≤ 5.5 V		60	190	μV/V
REF3020	(2.048 V)					
V <sub>OUT</sub>	Output voltage		2.044	2.048	2.052	V
	Initial accuracy				0.2%	
	Output valtage paige	f = 0.1 Hz to 10 Hz		23		$\mu V_{PP}$
	Output voltage noise	f = 10 Hz to 10 kHz		65		μVrms
	Line regulation	$V_{REF}$ + 50 mV $\leq$ $V_{IN}$ $\leq$ 5.5 V		110	290	μV/V
REF3025	(2.5 V)					
V <sub>OUT</sub>	Output voltage		2.495	2.50	2.505	V
	Initial accuracy				0.2%	
	0.1.1.1	f = 0.1 Hz to 10 Hz		28		$\mu V_{PP}$
RFF3030 (	Output voltage noise	f = 10 Hz to 10 kHz		80		μVrms
	Line regulation	$V_{REF}$ + 50 mV $\leq$ $V_{IN}$ $\leq$ 5.5 V		120	325	μV/V
REF3030	(3.0 V)				·	
V <sub>OUT</sub>	Output voltage		2.994	3.0	3.006 0.2%	V
	Initial accuracy				0.2%	
REF3020 (VOUT)  REF3025 (VOUT)  REF3030 (VOUT)	Outrot valtage as is a	f = 0.1 Hz to 10 Hz		33		$\mu V_{PP}$
	Output voltage noise	f = 10 Hz to 10 kHz		94		μVrms
	Line regulation	$V_{REF}$ + 50 mV $\leq$ $V_{IN}$ $\leq$ 5.5 V		120	375	μV/V
REF3033	(3.3 V)				·	
V <sub>OUT</sub>	Output voltage		3.294	3.30	3.306	V
	Initial accuracy				0.2%	
	Outrot valtage as is a	f = 0.1 Hz to 10 Hz		36		$\mu V_{PP}$
	Output voltage noise	f = 10 Hz to 10 kHz		105		μVrms
	Line regulation	$V_{REF}$ + 50 mV $\leq$ $V_{IN}$ $\leq$ 5.5 V		130	400	μV/V
REF3040	(4.096 V)					
V <sub>OUT</sub>	Output voltage		4.088	4.096	4.104	V
	Initial accuracy				0.2%	
REF3033 VOUT	Outrat valta as a sis	f = 0.1 Hz to 10 Hz		45		$\mu V_{PP}$
	Output voltage noise	f = 10 Hz to 10 kHz		128		μVrms
	Line regulation	$V_{RFF}$ + 50 mV $\leq$ $V_{IN}$ $\leq$ 5.5 V		160	410	μV/V

<sup>(1)</sup> The minimum supply voltage for the REF3012 is 1.8 V.

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### **Electrical Characteristics (continued)**

at  $T_A = 25$ °C,  $V_{IN} = 5$  V, and  $I_{LOAD} = 0$  mA (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
REF33xx (R	EF3312, REF3318, REF3320, REF33	25, REF3330, REF3333)				
		0°C ≤ T <sub>A</sub> ≤ 70°C		20	50	
dV <sub>OUT</sub> /dT (	0.4.4.1.1.1.1.1.1.1.1.1.1.1.1.1.1.1.1.1.	-30°C ≤ T <sub>A</sub> ≤ +85°C		28	60	/00
	Output voltage temperature drift <sup>(2)</sup>	–40°C ≤ T <sub>A</sub> ≤ +85°C		30	65	ppm/°C
		-40°C ≤ T <sub>A</sub> ≤ +125°C		35	75	
	Louis de sons de la litte.	0000h to 1000h		24		
	Long-term stability	1000h to 2000h		15	ppm	
$\Delta V_{O(\Delta IL)}$	Load regulation (3)	$0 \text{ mA} < I_{LOAD} < 25 \text{ mA}, V_{IN} = V_{REF} + 500 \text{ mV}^{(1)}$				μV/mA
dT	Thermal hysteresis <sup>(4)</sup>			25	100	ppm
V <sub>IN</sub> – V <sub>OUT</sub>	Dropout voltage			1	50	mV
I <sub>SC</sub>	Short-circuit current			45		mA
	Turn-on settling time	To 0.1% with $C_L = 1 \mu F$				ms
POWER SU	PPLY					
	0			42	50	
ΙQ	Quiescent current	–40°C ≤ T <sub>A</sub> ≤ +125°C			59	μA

<sup>(2)</sup> Box method used to determine over temperature drift.

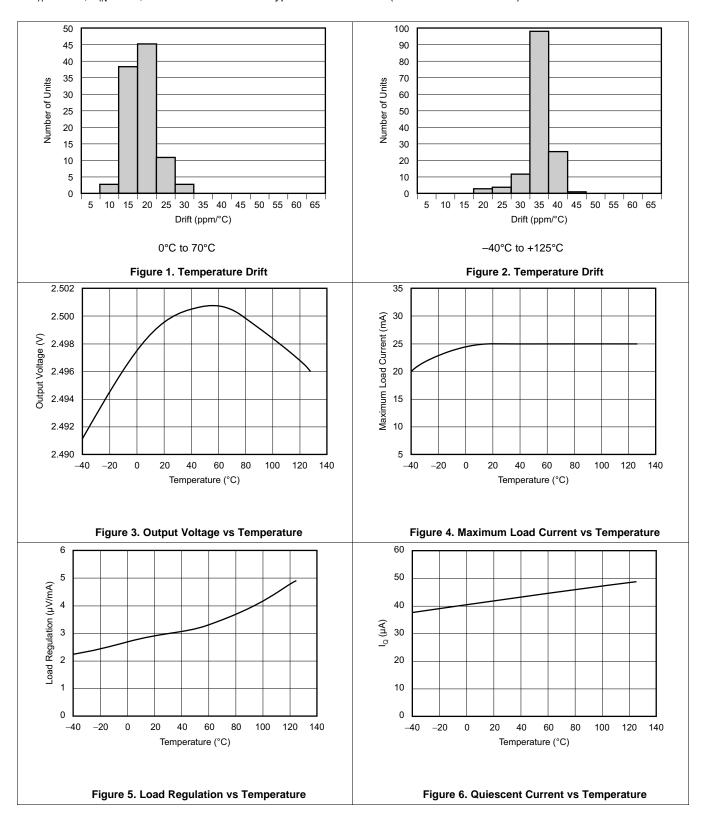
<sup>3)</sup> Typical value of load regulation reflects measurements using a force and sense contacts; see *Load Regulation* section.

<sup>(4)</sup> Thermal hysteresis procedure explained in more detail in *Thermal Hysteresis* section.



### 7.6 Typical Characteristics

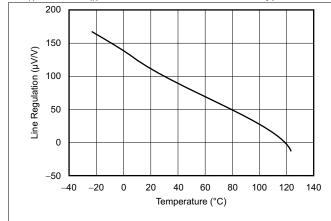
at  $T_A = 25$ °C,  $V_{IN} = 5$  V, and REF3025 used for typical characteristics (unless otherwise noted)



# TEXAS INSTRUMENTS

### **Typical Characteristics (continued)**

at T<sub>A</sub> = 25°C, V<sub>IN</sub> = 5 V, and REF3025 used for typical characteristics (unless otherwise noted)



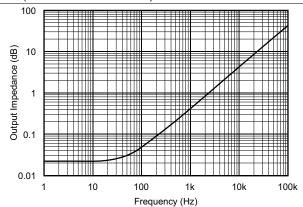
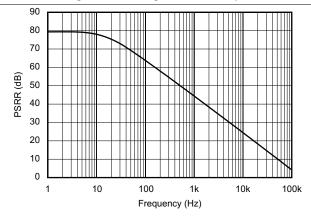


Figure 7. Line Regulation vs Temperature

Figure 8. Output Impedance vs Frequency



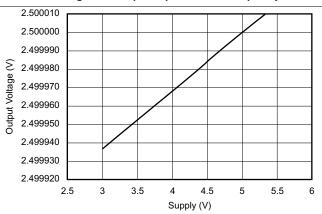
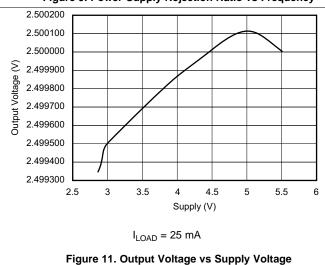


Figure 9. Power-Supply Rejection Ratio vs Frequency

Figure 10. Output Voltage vs Supply Voltage

No Load



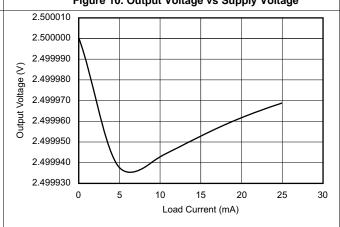
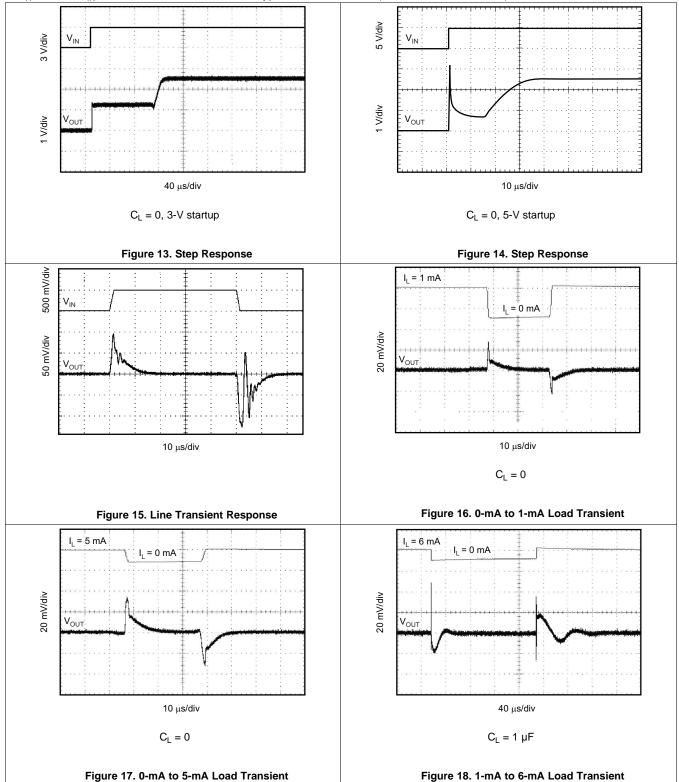


Figure 12. Output Voltage vs Load Current



### **Typical Characteristics (continued)**

at  $T_A = 25$ °C,  $V_{IN} = 5$  V, and REF3025 used for typical characteristics (unless otherwise noted)



### TEXAS INSTRUMENTS

### **Typical Characteristics (continued)**

at  $T_A = 25$ °C,  $V_{IN} = 5$  V, and REF3025 used for typical characteristics (unless otherwise noted)

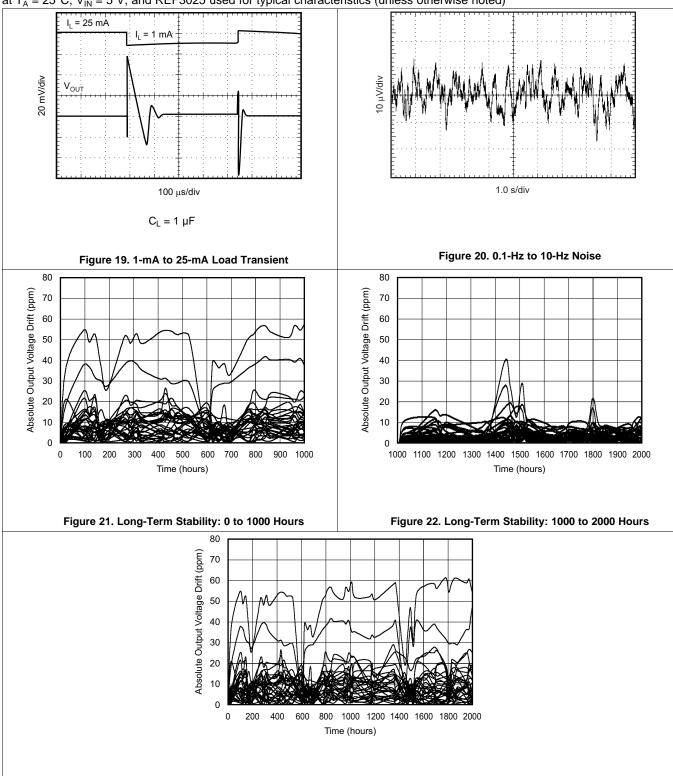


Figure 23. Long-Term Stability: 0 to 2000 Hours

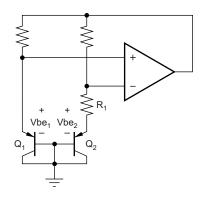


#### 8 Detailed Description

#### 8.1 Overview

The REF30xx is a series, CMOS, precision bandgap voltage reference. Its basic topology is shown in the *Functional Block Diagram* section. Transistors  $Q_1$  and  $Q_2$  are biased so that the current density of  $Q_1$  is greater than that of  $Q_2$ . The difference of the two base-emitter voltages,  $Vbe_1 - Vbe_2$ , has a positive temperature coefficient and is forced across resistor  $R_1$ . This voltage is gained up and added to the base-emitter voltage of  $Q_2$ , which has a negative coefficient. The resulting output voltage is virtually independent of temperature. The curvature of the bandgap voltage, as shown in Figure 3, is due to the slightly nonlinear temperature coefficient of the base-emitter voltage of  $Q_2$ .

#### 8.2 Functional Block Diagram



### 8.3 Feature Description

#### 8.3.1 Supply Voltage

The REF30xx family of references features an extremely low dropout voltage. With the exception of the REF3012, which has a minimum supply requirement of 1.8 V, the REF30xx can be operated with a supply of only 1 mV above the output voltage in an unloaded condition. For loaded conditions, a typical dropout voltage versus load is shown on the front page.

The REF30xx features a low quiescent current that is extremely stable over changes in both temperature and supply. The typical room temperature quiescent current is 42  $\mu$ A, and the maximum quiescent current over temperature is just 59  $\mu$ A. Additionally, the quiescent current typically changes less than 2.5  $\mu$ A over the entire supply range, as shown in Figure 24.

Supply voltages below the specified levels can cause the REF30xx to momentarily draw currents greater than the typical quiescent current. Use a power supply with a fast rising edge and low output impedance to easily prevent this issue.

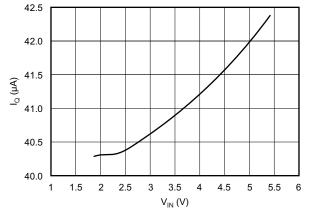


Figure 24. Supply Current vs Supply Voltage



#### **Feature Description (continued)**

#### 8.3.2 Thermal Hysteresis

Thermal hysteresis for the REF30xx is defined as the change in output voltage after operating the device at 25°C, cycling the device through the specified temperature range, and returning to 25°C, and can be expressed as shown in Equation 1:

$$V_{HYST} = \left(\frac{abs|V_{PRE} - V_{POST}|}{V_{NOM}}\right) \cdot 10^6 \text{ (ppm)}$$

#### where

- V<sub>HYST</sub> = Calculated hysteresis
- V<sub>PRE</sub> = Output voltage measured at 25°C pretemperature cycling
- V<sub>POST</sub> = Output voltage measured when device has been operated at 25°C, cycled through specified range of
   —40°C to +125°C, and returned to operation at 25°C.

#### 8.3.3 Temperature Drift

The REF30xx exhibits minimal drift error, defined as the change in output voltage over varying temperature. Using the *box* method of drift measurement, the REF30xx features a typical drift coefficient of 20 ppm from 0°C to 70°C, the primary temperature range of use for many applications. For industrial temperature ranges of –40°C to +125°C, the REF30xx family drift increases to a typical value of 50 ppm.

#### 8.3.4 Noise Performance

The REF30xx generates noise less than 50  $\mu$ V<sub>PP</sub> between frequencies of 0.1 Hz to 10 Hz, and can be seen in Figure 20 The noise voltage of the REF30xx increases with output voltage and operating temperature. Additional filtering may be used to improve output noise levels; however, ensure the output impedance does not degrade ac performance.

#### 8.3.5 Long-Term Stability

Long-term stability refers to the change of the output voltage of a reference over a period of months or years. This effect lessens as time progresses as is apparent by the long term stability curves. The typical drift value for the REF30xx is 24 ppm from 0 hours to 1000 hours, and 15 ppm from 1000 hours to 2000 hours. This parameter is characterized by measuring 30 units at regular intervals for a period of 2000 hours.

#### 8.3.6 Load Regulation

Load regulation is defined as the change in output voltage as a result of changes in load current. Load regulation for the REF30xx is measured using force and sense contacts as shown in Figure 25. The force and sense lines tied to the contact area of the output pin reduce the impact of contact and trace resistance, resulting in accurate measurement of the load regulation contributed solely by the REF30xx. For applications requiring improved load regulation, use force and sense lines.

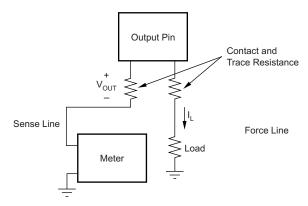


Figure 25. Accurate Load Regulation of REF30xx



#### 8.4 Device Functional Modes

#### 8.4.1 Negative Reference Voltage

For applications requiring a negative and positive reference voltage, the OPA703 and REF30xx can be used to provide a dual supply reference from a ±5-V supply. Figure 26 shows the REF3025 used to provide a ±2.5-V supply reference voltage. The low offset voltage and low drift of the OPA703 complement the low drift performance of the REF30xx to provide an accurate solution for split-supply applications.

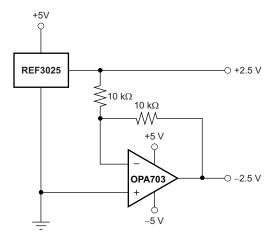


Figure 26. REF3025 Combined With OPA703 to Create Positive and Negative Reference Voltages.

#### 8.4.2 Data Acquisition

Often data acquisition systems require stable voltage references to maintain necessary accuracy. The REF30xx family features stability and a wide range of voltages suitable for most microcontrollers and data converters. Figure 27 and Figure 28 show two basic data acquisition systems.

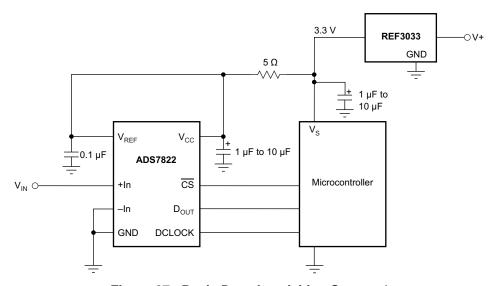


Figure 27. Basic Data Acquisition System 1



### **Device Functional Modes (continued)**

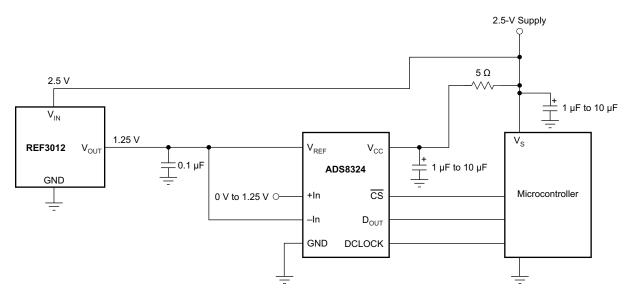


Figure 28. Basic Data Acquisition System 2



### 9 Application and Implementation

#### 9.1 Application Information

For normal operation, the REF30xx does not require a capacitor on the output. If a capacitive load is connected, take special care when using low equivalent series resistance (ESR) capacitors and high capacitance. This precaution is especially true for low-output voltage devices; therefore, for the REF3012 use a low-ESR capacitance of 10  $\mu$ F or less. Figure 29 shows the typical connections required for operation of the REF30xx. A supply bypass capacitor of 0.47  $\mu$ F is always recommended.

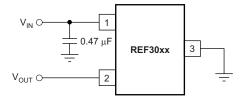


Figure 29. Typical Connections for Operating REF30xx

### 9.2 Typical Application

Figure 30 shows a low-power reference and conditioning circuit. This circuit attenuates and level-shifts a bipolar input voltage within the proper input range of a single-supply low power 16-Bit  $\Delta\Sigma$  ADC, such as the one inside the MSP430 or other similar single-supply ADCs. Precision reference circuits are used to level-shift the input signal, provide the ADC reference voltage and to create a well-regulated supply voltage for the low-power analog circuitry. A low-power, zero-drift, op-amp circuit is used to attenuate and level-shift the input signal.

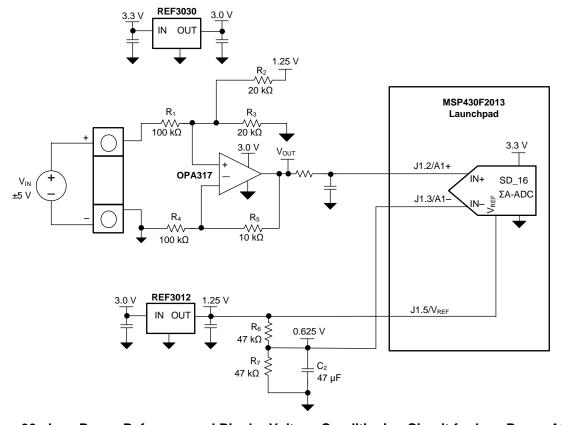


Figure 30. Low-Power Reference and Bipolar Voltage Conditioning Circuit for Low-Power ADCs



#### **Typical Application (continued)**

### 9.2.1 Design Requirements

Supply Voltage: 3.3 V

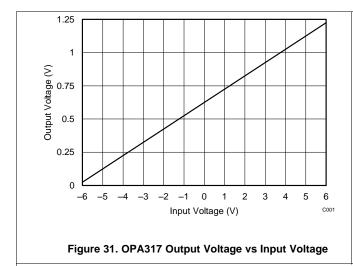
Maximum Input Voltage: ±6 V
 Specified Input Voltage: ±5 V
 ADC Reference Voltage: 1.25 V

The goal for this design is to accurately condition a  $\pm 5$ -V bipolar input voltage into a voltage suitable for conversion by a low-voltage ADC with a 1.25-V reference voltage,  $V_{REF}$ , and an input voltage range of  $V_{REF}$  / 2. The circuit should function with reduced performance over a wider input range of at least  $\pm 6$  V to allow for easier protection of overvoltage conditions.

### 9.2.2 Detailed Design Procedure

Figure 30 depicts a simplified schematic for this design showing the MSP430 ADC inputs and full input conditioning circuitry. The ADC is configured for a bipolar measurement where final conversion result is the differential voltage between the voltage at the positive and negative ADC inputs. The bipolar, GND referenced input signal must be level-shifted and attenuated by the op amp so that the output is biased to VREF / 2 and has a differential voltage that is within the ±VREF / 2 input range of the ADC.

#### 9.2.3 Application Curves



-0.0001 -0.00015 Error Voltage (V) -0.0002 -0.00025 -0.0003 -0.00035 -5 -4 -3 -6 -2 -1 0 1 2 5 6 Input Voltage (V)

Figure 32. OPA317 Output Voltage Error vs Input Voltage

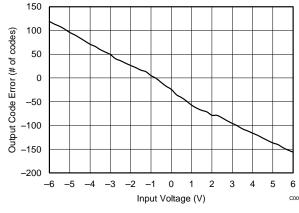


Figure 33. Output Code Error vs Input Voltage



### 10 Power Supply Recommendations

The REF30xx family of references feature an extremely low-dropout voltage. These references can be operated with a supply of only 50 mV above the output voltage. For loaded reference conditions, a typical dropout voltage versus load is shown in the front page plot, *Dropout Voltage vs Load Current*. Use a supply bypass capacitor greater than  $0.47 \, \mu F$ .

### 11 Layout

### 11.1 Layout Guidelines

Figure 34 illustrates an example of a printed circuit board (PCB) layout using the REF30xx. Some key considerations are:

- Connect low-ESR, 0.1-μF ceramic bypass capacitors at V<sub>IN</sub> of the REF30xx
- Decouple other active devices in the system per the device specifications
- Use a solid ground plane to help distribute heat and reduces electromagnetic interference (EMI) noise pickup
- Place the external components as close to the device as possible. This configuration prevents parasitic errors (such as the Seebeck effect) from occurring
- Minimize trace length between the reference and bias connections to the INA and ADC to reduce noise pickup
- Do not run sensitive analog traces in parallel with digital traces. Avoid crossing digital and analog traces if possible, and only make perpendicular crossings when absolutely necessary

### 11.2 Layout Example

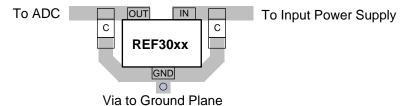


Figure 34. Layout Example



Click here

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### 12 Device and Documentation Support

#### 12.1 Documentation Support

#### 12.1.1 Related Documentation

OPA703 Data Sheet, SBOS180

REF29xx Data Sheet, SBVS033

#### 12.2 Related Links

**PARTS** 

REF3012

REF3020

REF3025

REF3030

REF3033

REF3040

Table 1 lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

**SUPPORT & TOOLS &** PRODUCT FOLDER **SAMPLE & BUY** COMMUNITY **DOCUMENTS SOFTWARE** Click here Click here

Click here

Click here

Click here

Click here

**Table 1. Related Links** 

### 12.3 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

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#### 12.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### 12.6 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

### 13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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16-Dec-2015

### **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
REF3012AIDBZR	ACTIVE	SOT-23	DBZ	3	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	R30A	Sample
REF3012AIDBZRG4	ACTIVE	SOT-23	DBZ	3	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	R30A	Sample
REF3012AIDBZT	ACTIVE	SOT-23	DBZ	3	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	R30A	Sample
REF3012AIDBZTG4	ACTIVE	SOT-23	DBZ	3	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	R30A	Sample
REF3020AIDBZR	ACTIVE	SOT-23	DBZ	3	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	R30B	Sample
REF3020AIDBZRG4	ACTIVE	SOT-23	DBZ	3	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	R30B	Sample
REF3020AIDBZT	ACTIVE	SOT-23	DBZ	3	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	R30B	Sample
REF3020AIDBZTG4	ACTIVE	SOT-23	DBZ	3	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	R30B	Sample
REF3025AIDBZR	ACTIVE	SOT-23	DBZ	3	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	R30C	Sample
REF3025AIDBZRG4	ACTIVE	SOT-23	DBZ	3	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	R30C	Sample
REF3025AIDBZT	ACTIVE	SOT-23	DBZ	3	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	R30C	Sample
REF3025AIDBZTG4	ACTIVE	SOT-23	DBZ	3	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	R30C	Sample
REF3030AIDBZR	ACTIVE	SOT-23	DBZ	3	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	R30F	Sample
REF3030AIDBZRG4	ACTIVE	SOT-23	DBZ	3	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	R30F	Sample
REF3030AIDBZT	ACTIVE	SOT-23	DBZ	3	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	R30F	Sample
REF3030AIDBZTG4	ACTIVE	SOT-23	DBZ	3	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	R30F	Sample
REF3033AIDBZR	ACTIVE	SOT-23	DBZ	3	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	R30D	Sample



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### PACKAGE OPTION ADDENDUM

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Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
REF3033AIDBZRG4	ACTIVE	SOT-23	DBZ	3	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	R30D	Samples
REF3033AIDBZT	ACTIVE	SOT-23	DBZ	3	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	R30D	Samples
REF3033AIDBZTG4	ACTIVE	SOT-23	DBZ	3	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	R30D	Samples
REF3040AIDBZR	ACTIVE	SOT-23	DBZ	3	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	R30E	Samples
REF3040AIDBZRG4	ACTIVE	SOT-23	DBZ	3	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	R30E	Samples
REF3040AIDBZT	ACTIVE	SOT-23	DBZ	3	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	R30E	Samples
REF3040AIDBZTG4	ACTIVE	SOT-23	DBZ	3	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	R30E	Samples

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.



### PACKAGE OPTION ADDENDUM

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(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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#### OTHER QUALIFIED VERSIONS OF REF3033:

Automotive: REF3033-Q1

NOTE: Qualified Version Definitions:

• Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

### PACKAGE MATERIALS INFORMATION

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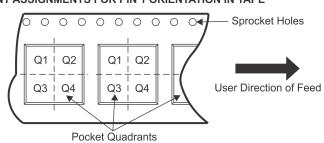
### TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

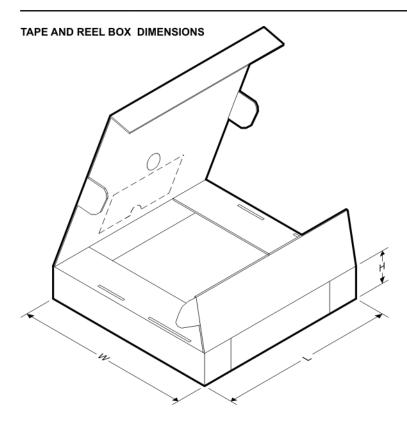


#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
REF3012AIDBZR	SOT-23	DBZ	3	3000	179.0	8.4	3.15	2.95	1.22	4.0	8.0	Q3
REF3012AIDBZT	SOT-23	DBZ	3	250	179.0	8.4	3.15	2.95	1.22	4.0	8.0	Q3
REF3020AIDBZR	SOT-23	DBZ	3	3000	179.0	8.4	3.15	2.95	1.22	4.0	8.0	Q3
REF3020AIDBZT	SOT-23	DBZ	3	250	179.0	8.4	3.15	2.95	1.22	4.0	8.0	Q3
REF3025AIDBZR	SOT-23	DBZ	3	3000	179.0	8.4	3.15	2.95	1.22	4.0	8.0	Q3
REF3025AIDBZT	SOT-23	DBZ	3	250	179.0	8.4	3.15	2.95	1.22	4.0	8.0	Q3
REF3030AIDBZR	SOT-23	DBZ	3	3000	179.0	8.4	3.15	2.95	1.22	4.0	8.0	Q3
REF3030AIDBZT	SOT-23	DBZ	3	250	179.0	8.4	3.15	2.95	1.22	4.0	8.0	Q3
REF3033AIDBZR	SOT-23	DBZ	3	3000	179.0	8.4	3.15	2.95	1.22	4.0	8.0	Q3
REF3033AIDBZT	SOT-23	DBZ	3	250	179.0	8.4	3.15	2.95	1.22	4.0	8.0	Q3
REF3040AIDBZR	SOT-23	DBZ	3	3000	179.0	8.4	3.15	2.95	1.22	4.0	8.0	Q3
REF3040AIDBZT	SOT-23	DBZ	3	250	179.0	8.4	3.15	2.95	1.22	4.0	8.0	Q3

**PACKAGE MATERIALS INFORMATION** 

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\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
REF3012AIDBZR	SOT-23	DBZ	3	3000	203.0	203.0	35.0
REF3012AIDBZT	SOT-23	DBZ	3	250	203.0	203.0	35.0
REF3020AIDBZR	SOT-23	DBZ	3	3000	203.0	203.0	35.0
REF3020AIDBZT	SOT-23	DBZ	3	250	203.0	203.0	35.0
REF3025AIDBZR	SOT-23	DBZ	3	3000	203.0	203.0	35.0
REF3025AIDBZT	SOT-23	DBZ	3	250	203.0	203.0	35.0
REF3030AIDBZR	SOT-23	DBZ	3	3000	203.0	203.0	35.0
REF3030AIDBZT	SOT-23	DBZ	3	250	203.0	203.0	35.0
REF3033AIDBZR	SOT-23	DBZ	3	3000	203.0	203.0	35.0
REF3033AIDBZT	SOT-23	DBZ	3	250	203.0	203.0	35.0
REF3040AIDBZR	SOT-23	DBZ	3	3000	203.0	203.0	35.0
REF3040AIDBZT	SOT-23	DBZ	3	250	203.0	203.0	35.0

# DBZ (R-PDSO-G3)

### PLASTIC SMALL-OUTLINE



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Lead dimensions are inclusive of plating.
- D. Body dimensions are exclusive of mold flash and protrusion. Mold flash and protrusion not to exceed 0.25 per side.
- Falls within JEDEC TO-236 variation AB, except minimum foot length.



# DBZ (R-PDSO-G3)

### PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



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